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|  | <h2 style="color: red;">FQD24N08TF</h2> |
| | <p>Hersteller-Teilenummer: FQD24N08TF</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 80V 19.6A DPAK</p> <p>Datenblätter: 1.FQD24N08TF.pdf 2.FQD24N08TF.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 12401 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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| Teilenummer | FQD24N08TF |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 80V 19.6A DPAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 12401 pcs Stock |
| detaillierte Beschreibung | N-Channel 80V 19.6A (Tc) 2.5W (Ta), 50W (Tc) |
| Serie | QFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-252-3, DPak (2 Leads + Tab), SC-63 |
| Supplier Device-Gehäuse | D-Pak |
| Verlustleistung (max) | 2.5W (Ta), 50W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 80V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 19.6A (Tc) |
| Rds On (Max) @ Id, Vgs | 60 mOhm @ 9.8A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 25nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 750pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±25V |
| Verpackung | Tape & Reel (TR) |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |

FQD24N08TF ist neu im Original, Suche FQD24N08TF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD24N08TF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD24N08TF: Info@Y-IC.com

Sie können auch interessiert sein:

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|  <p>FQD2N100TF Fairchild/ON Semiconductor MOSFET N-CH 1000V 1.6A DPAK</p> |  <p>FQD24N08TM Fairchild/ON Semiconductor MOSFET N-CH 80V 19.6A DPAK</p> |  <p>FQD20N06TM Fairchild/ON Semiconductor MOSFET N-CH 60V 16.8A DPAK</p> |  <p>FQD25N06 FAIRCHI FAIRCHI TO252</p> |
|  <p>FQD24N08TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 19.6A DPAK</p> |  <p>FQD20N06TF AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 16.8A DPAK</p> |  <p>FQD24N08 FAIRCHILD FQD24N08 FAIRCHILD</p> |  <p>FQD20N06TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 16.8A DPAK</p> |

heiße Teile

Mehr

| | | | | |
|-------------------|---------------|----------------|-----------------|-------------------|
| ⊗ FQD1N60TF | ↔ FQD1N60TF | ⇒ FQD1N60TM | D FQD1N60TM | ⇒ FQD1N80TM |
| ⊕ FQD1N80TM | ⊗ FQD1P50TM | D FQD1P50TM | ⇒ FQD20N06 | ⇒ FQD20N06-NL |
| ⊗ FQD20N06L | ⊕ FQD20N06LE | ⊗ FQD20N06LETM | ↔ FQD20N06LETM | ⇒ FQD20N06LTF |
| D FQD20N06LTF | ⊗ FQD20N06LTM | ⊕ FQD20N06LTM | ⊗ FQD20N06LTU | ⇒ FQD20N06TF |
| ⇒ FQD20N06TF | ↔ FQD20N06TM | ⊗ FQD20N06TM | ⊕ FQD24N08 | ⇒ FQD24N08TF |
| ↔ FQD24N08TM | ⇒ FQD24N08TM | D FQD2N100 | ⊗ FQD2N100TM | ⊕ FQD2N100TM |
| ⊗ FQD2N30TF | D FQD2N40TM | ⇒ FQD2N40TM | ↔ FQD2N50B | ⇒ FQD2N50C |
| ⊕ FQD2N50TF | ⊗ FQD2N50TF | ↔ FQD2N50TM | ⇒ FQD2N50TM | ⇒ FQD2N60A |
| ⊗ FQD2N60C | ⊕ FQD2N60CTF | ⊗ FQD2N60CTF | D FQD2N60CTF-NL | ⇒ FQD2N60CTF_F080 |
| ↔ FQD2N60CTF_F080 | ⊗ FQD2N60CTM | ⊕ FQD2N60CTM | ⊗ FQD2N60TM | ⇒ FQD2N60TM |

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